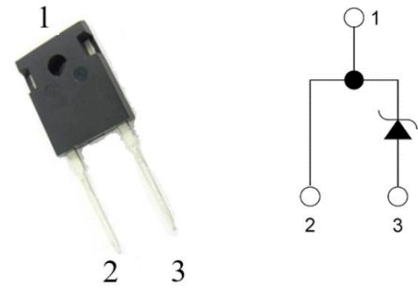


Product Summary

$V_R = 1700\text{ V}$
 $I_F = 20\text{ A}$ ($T_C=150^\circ\text{C}$)
 $Q_c = 202\text{ nC}$ ($V_R=1700\text{ V}$)



TO-247-2

Features

- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on V_F
- Temperature Independent Switching Behavior
- High surge current capability
- 100% avalanche tested

Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

Applications

- Motor Drives
- Solar / Wind Inverters
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies

Maximum Ratings ($T_C=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		1700	V
Continuous Forward Current	I_F	$T_C=25^\circ\text{C}$	54	A
		$T_C=135^\circ\text{C}$	26	
		$T_C=150^\circ\text{C}$	20	
Non repetitive Forward Surge Current	I_{FSM}	$T_C = 25^\circ\text{C}$, $t_p=10\text{ ms}$, Half Sine Pulse	205	A
		$T_C = 110^\circ\text{C}$, $t_p=10\text{ ms}$, Half Sine Pulse	190	
Repetitive peak Forward Surge Current	I_{FRM}	$T_C = 25^\circ\text{C}$, $t_p=10\text{ ms}$, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	155	A
		$T_C = 110^\circ\text{C}$, $t_p=10\text{ ms}$, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	140	
Total power dissipation	P_D	$T_C=25^\circ\text{C}$	333	W
		$T_C=110^\circ\text{C}$	144	
Operating Junction Temperature	T_J		-55 to 175	$^\circ\text{C}$
Storage Temperature	T_{STG}		-55 to 175	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Electrical Characteristics

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	V_{DC}	$T_J = 25^{\circ}C$	1700			V
Forward Voltage	V_F	$I_F = 20A, T_J = 25^{\circ}C$		1.45	1.75	V
		$I_F = 20A, T_J = 125^{\circ}C$		1.9		
		$I_F = 20A, T_J = 175^{\circ}C$		2.3		
Reverse Current	I_R	$V_R = 1700V, T_J = 25^{\circ}C$		2	150	uA
		$V_R = 1700V, T_J = 125^{\circ}C$		12		
		$V_R = 1700V, T_J = 175^{\circ}C$		50		
Total Capacitive Charge	Q_C	$V_R = 1700V, T_J = 25^{\circ}C$		202		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^{\circ}C,$ Freq = 1MHz		1415		pF
		$V_R = 800V, T_J = 25^{\circ}C,$ Freq = 1MHz		89		
		$V_R = 1200V, T_J = 25^{\circ}C,$ Freq = 1MHz		83		
		$V_R = 1700V, T_J = 25^{\circ}C,$ Freq = 1MHz		79		

Note: This is a majority carrier diode, so there is no reverse recovery charge

Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		0.45		$^{\circ}C/W$

Typical Electrical Curves

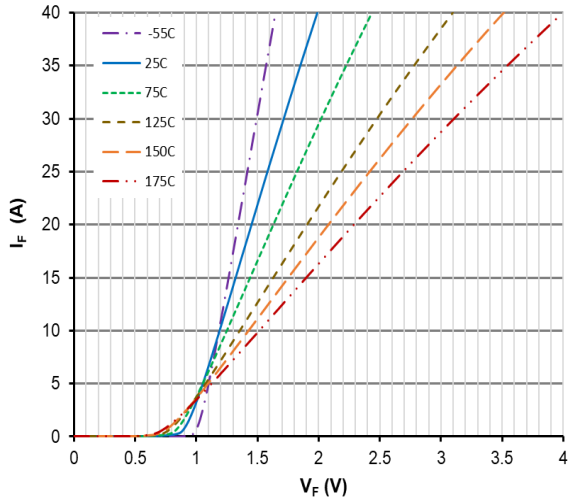


Figure 1. Forward Characteristics

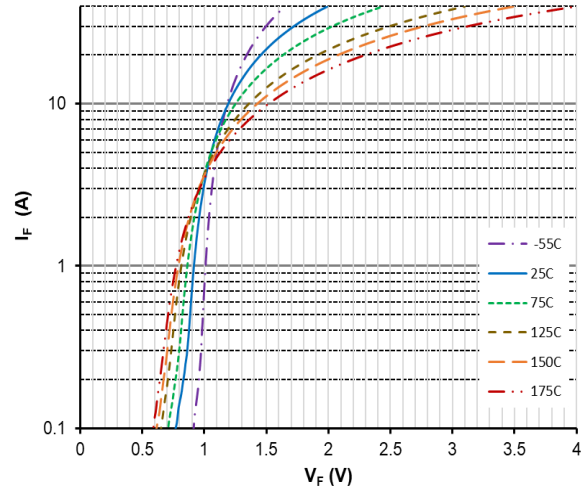


Figure 2. Forward Characteristics

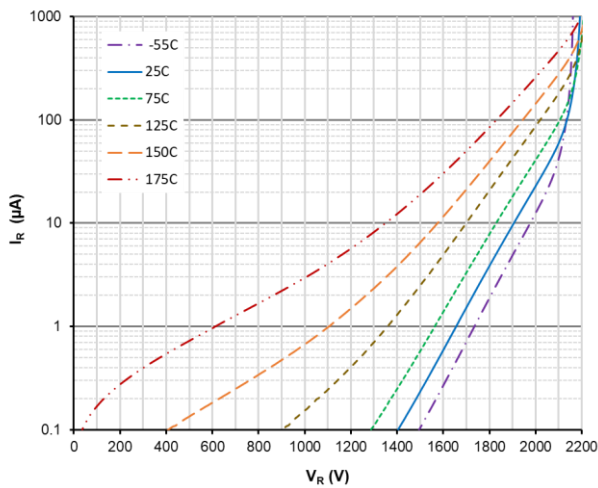


Figure 3. Reverse Characteristics

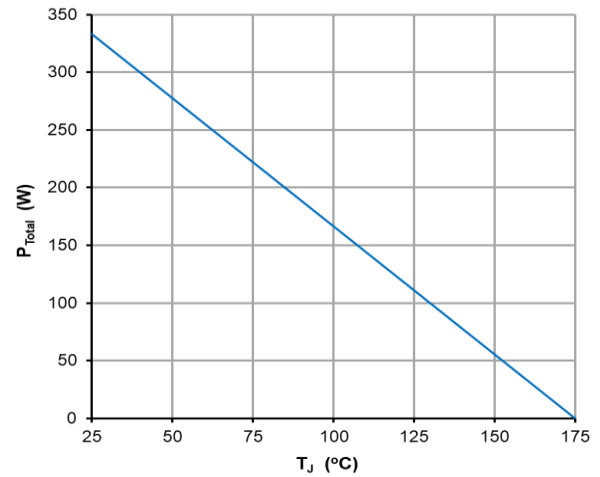


Figure 4. Power Derating

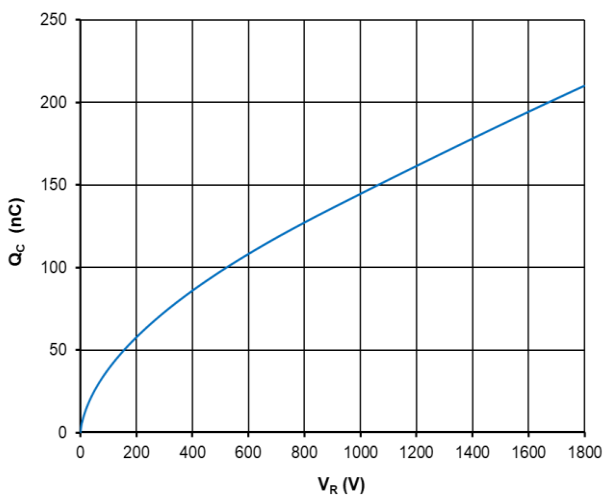


Figure 5. Reverse charge vs. Reverse Voltage

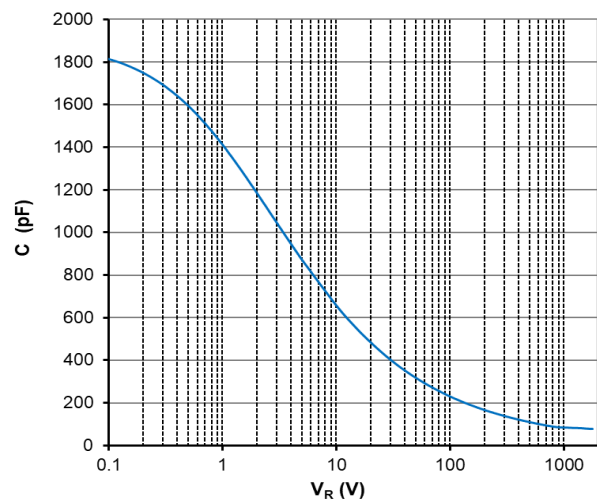


Figure 6. Capacitance vs. Reverse Voltage

Typical Electrical Curves

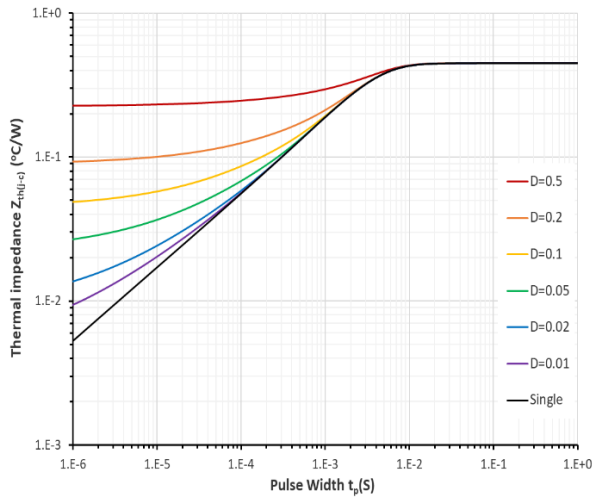


Figure 7. Transient Thermal Impedance

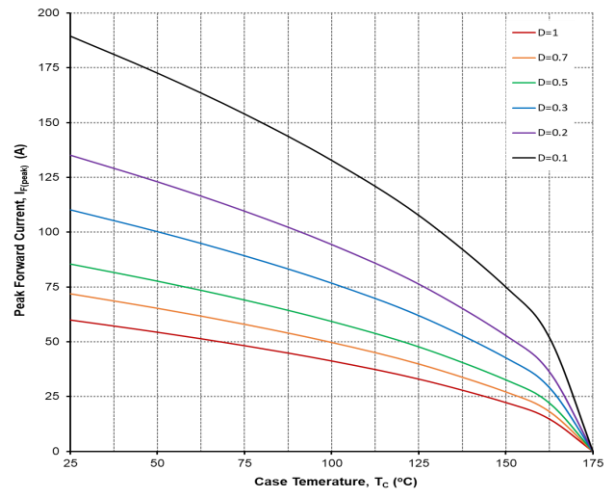
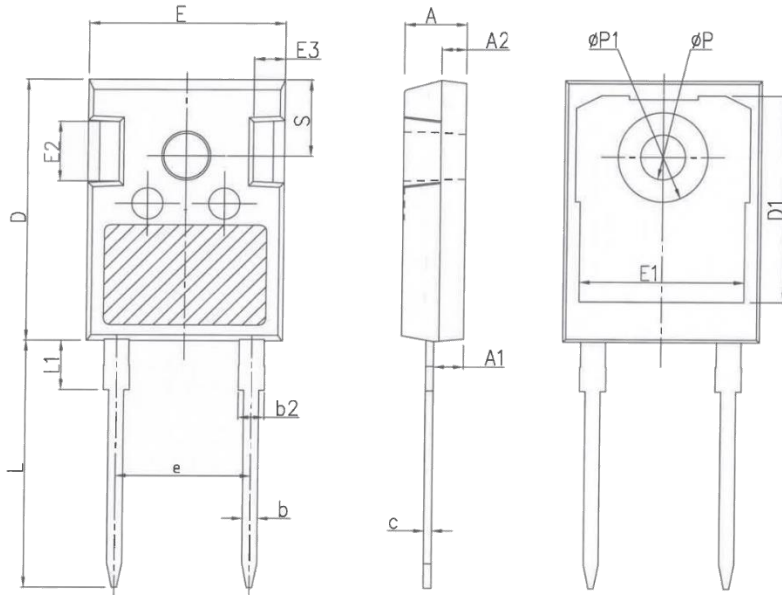


Figure 8. Current Derating

Package Dimensions

(TO-247-2 Package)



SYMBOL	mm	
	MIN.	MAX
A	4.8	5.20
A1	2.21	2.59
A2	1.85	2.15
b	1.11	1.36
b2	1.91	2.21
c	0.51	0.75
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.00	13.60
E2	4.80	5.20
E3	2.30	2.70
e	10.88BSC	
L	19.62	20.22
L1	-	4.30
φP	3.4	3.80
φP1	-	7.30
S	6.15BSC	

Part Number	Package	Packing	Marking
A3D20PS170AN	TO-247-2	30pcs / Tube	A3D20PS170AN